



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

CPH3140 / CPH3240 — High-Voltage Switching Applications

PNP / NPN Epitaxial Planar Silicon Transistors

Features

- Adoption of FBIT, MBIT processes
- High breakdown voltage and large current capacity
- High-speed switching
- Ultrasmall size making it easy to provide high-density, small-sized hybrid ICs

Specifications (): CPH3140

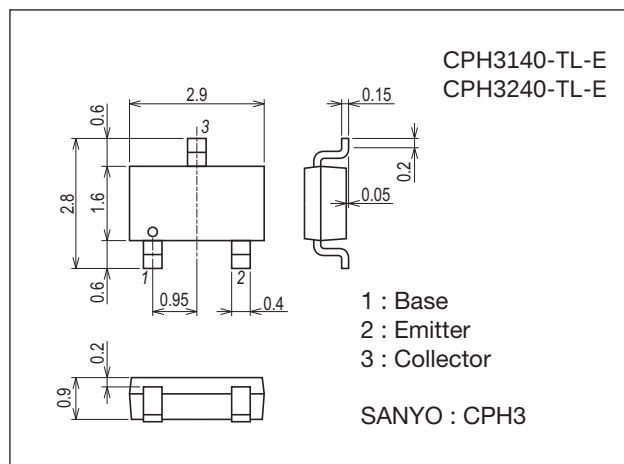
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-)120	V
Collector-to-Emitter Voltage	V _{CEO}		(-)100	V
Emitter-to-Base Voltage	V _{EB0}		(-)6	V
Collector Current	I _C		(-)1	A
Collector Current (Pulse)	I _{CP}		(-)2	A
Collector Dissipation	P _C	When mounted on ceramic substrate (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Package Dimensions

unit : mm (typ)

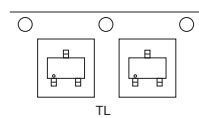
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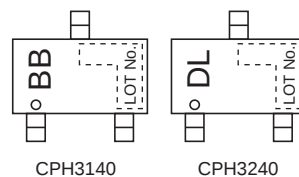
Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

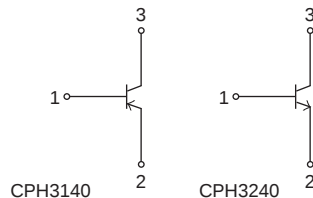
Packing Type: TL



Marking



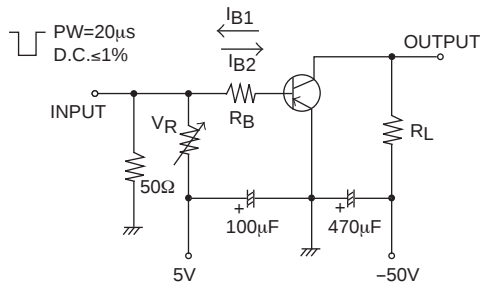
Electrical Connection



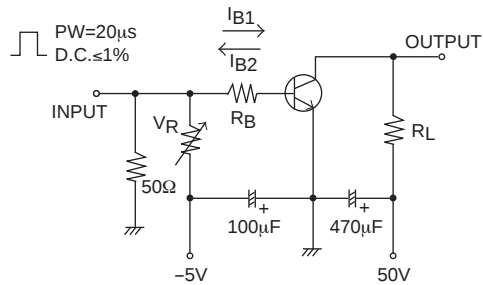
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)100V, I_E=0A$			$(-)\text{100}$	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4V, I_C=0A$			$(-)\text{100}$	nA
DC Current Gain	h_{FE}	$V_{CE}=(-)10V, I_C=(-)100mA$	140		400	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10V, I_C=(-)100mA$		120		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		(13)8.5		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)400mA, I_B=(-)40mA$		$(-0.2)0.1$	$(-0.6)0.4$	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)400mA, I_B=(-)40mA$		$(-)0.85$	$(-)1.2$	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0A$	$(-)\text{120}$			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	$(-)\text{100}$			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0A$	$(-)\text{6}$			V
Turn-On Time	t_{on}	See specified Test Circuit.		(80)80		ns
Storage Time	t_{stg}			(700)850		ns
Fall Time	t_f			(40)50		ns

Switching Time Test Circuit



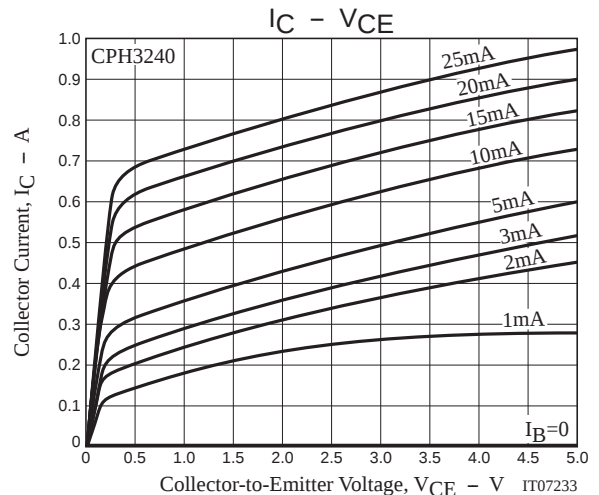
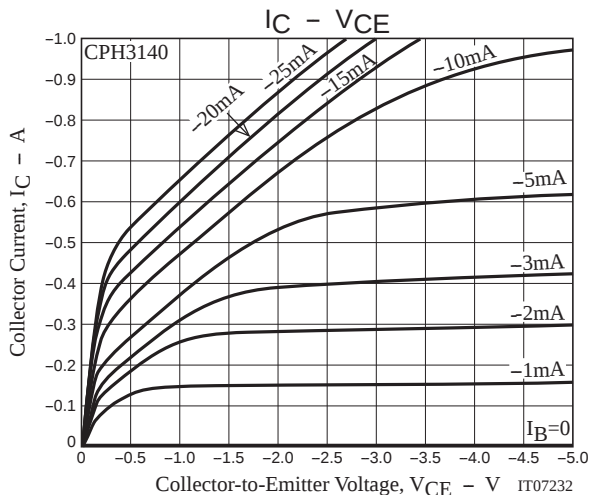
$I_C = -10I_{B1} = 10I_{B2} = -400mA$
CPH3140

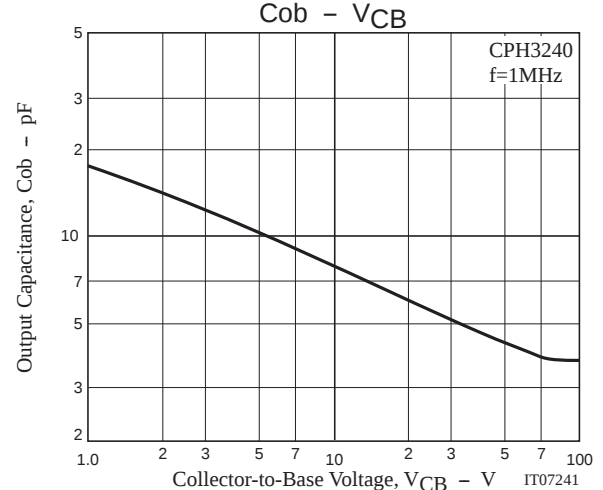
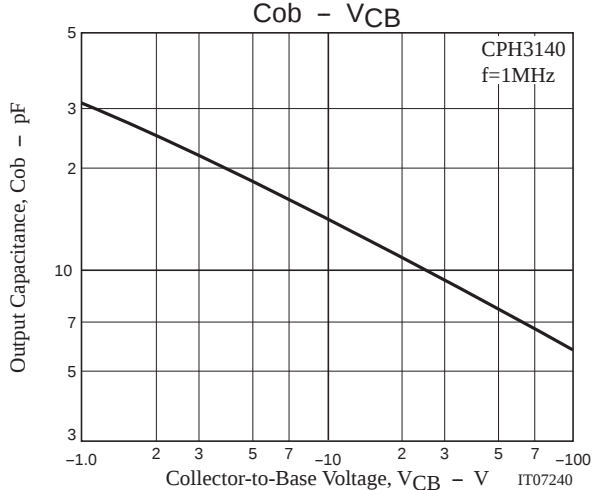
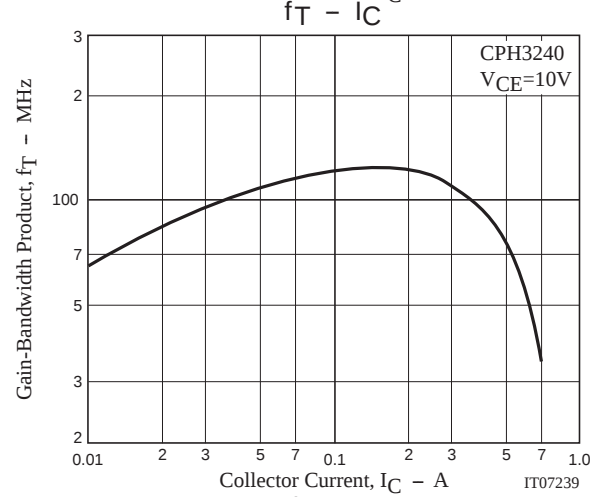
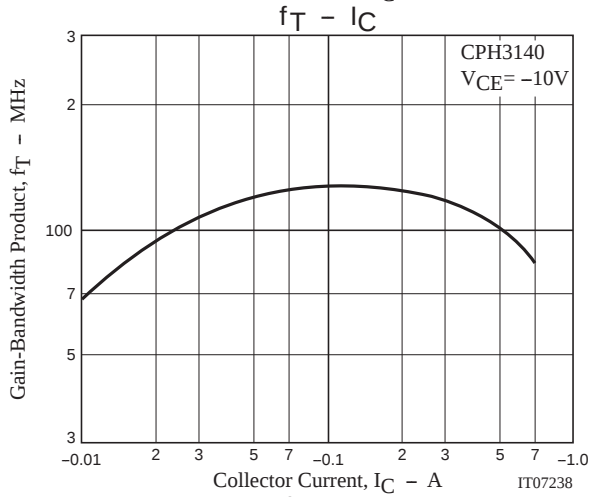
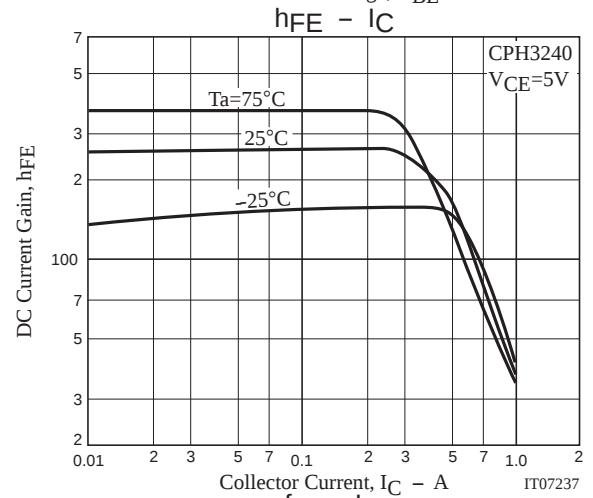
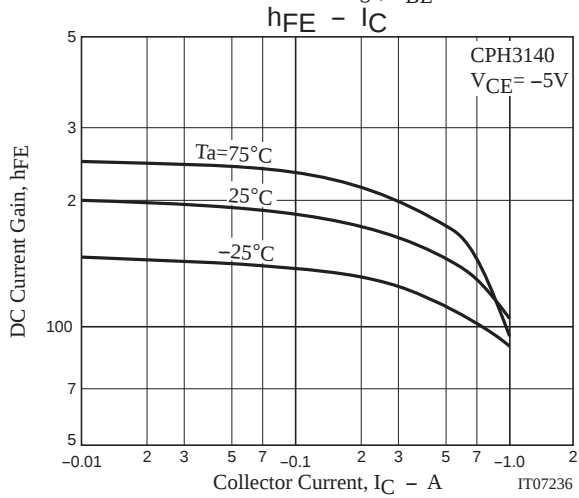
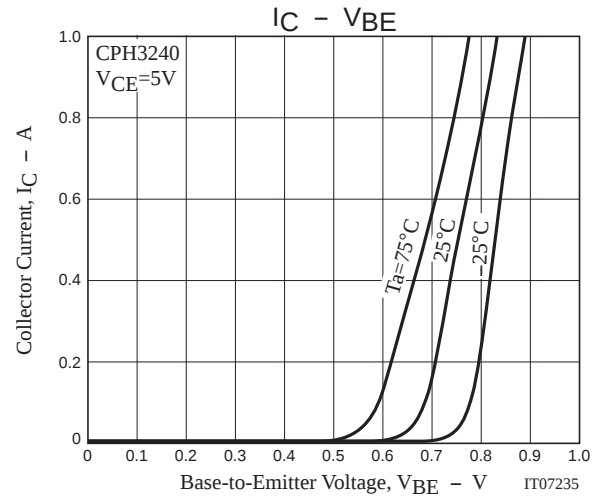
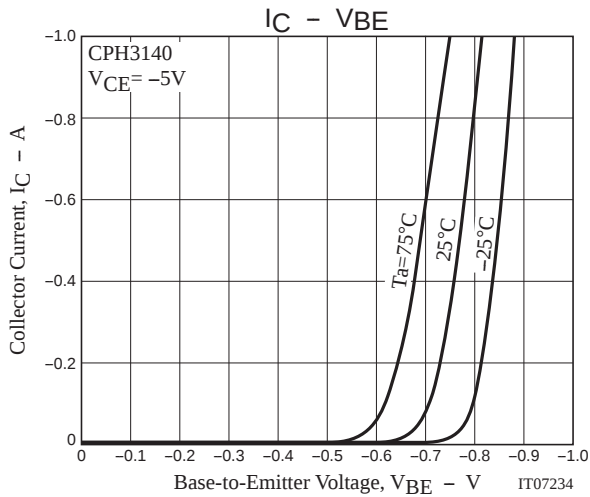


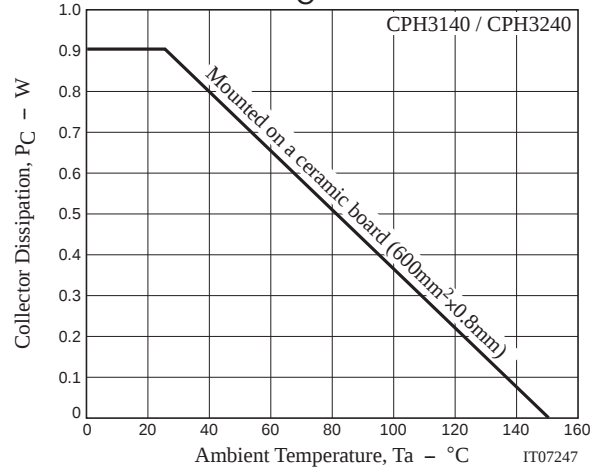
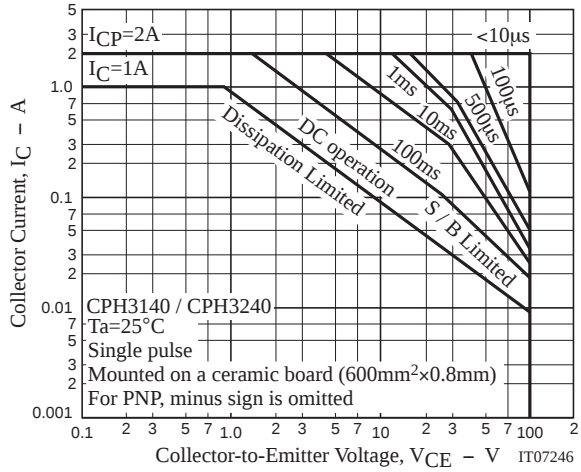
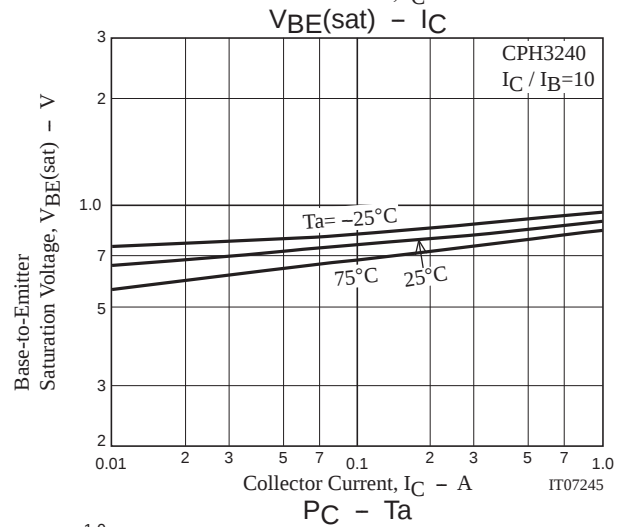
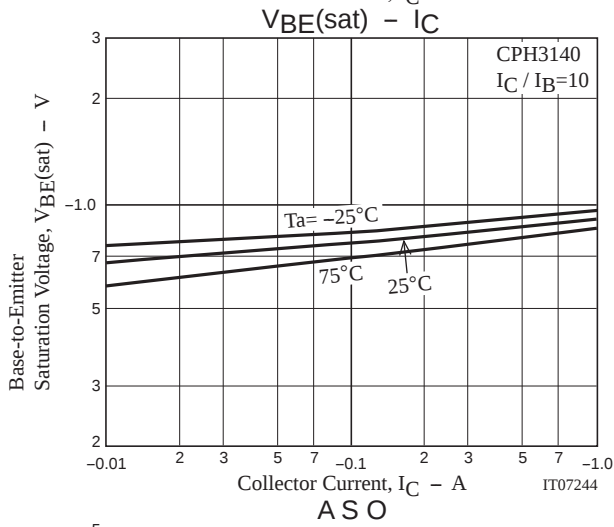
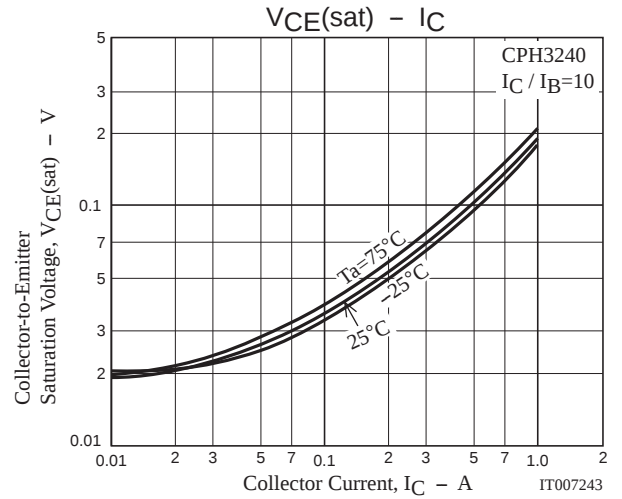
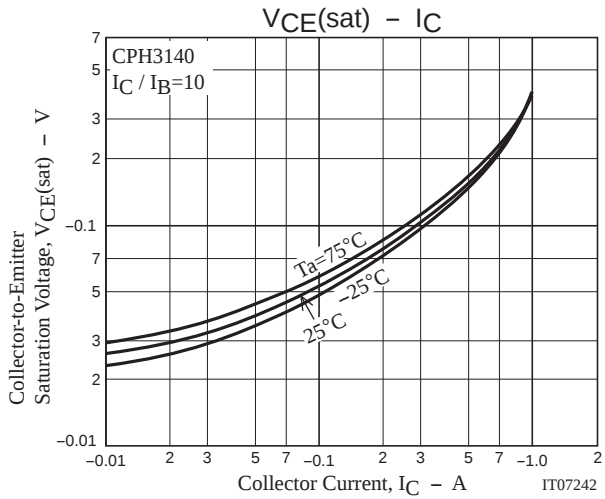
$I_C = 10I_{B1} = -10I_{B2} = 400mA$
CPH3240

Ordering Information

Device	Package	Shipping	memo
CPH3140-TL-E	CPH3	3,000pcs./reel	Pb Free
CPH3240-TL-E	CPH3	3,000pcs./reel	Pb Free







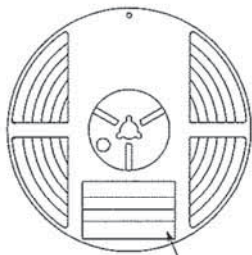
Embossed Taping Specification

CPH3140-TL-E, CPH3240-TL-E

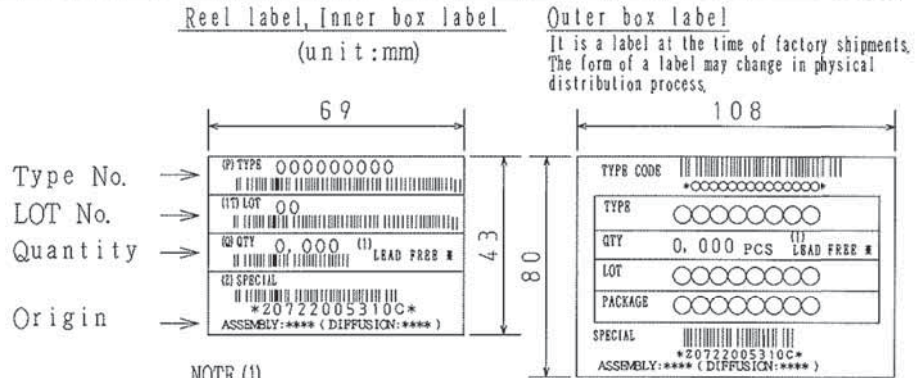
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH3	CPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method

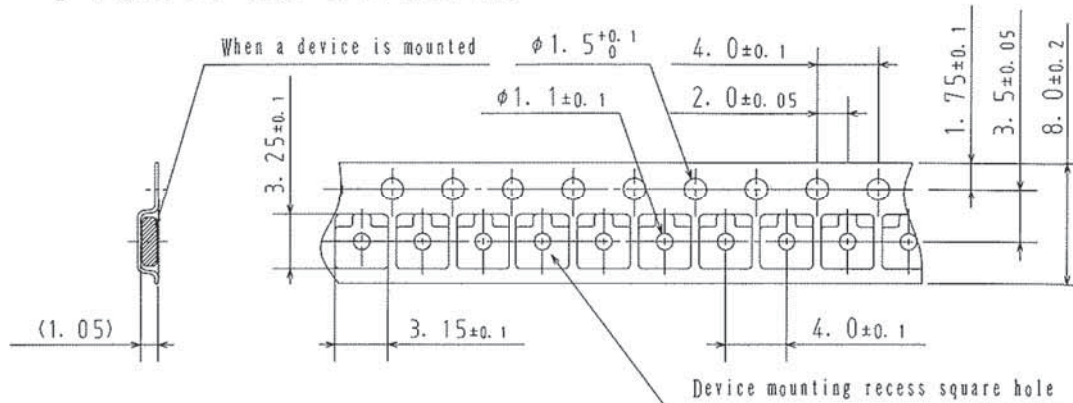


Reel label

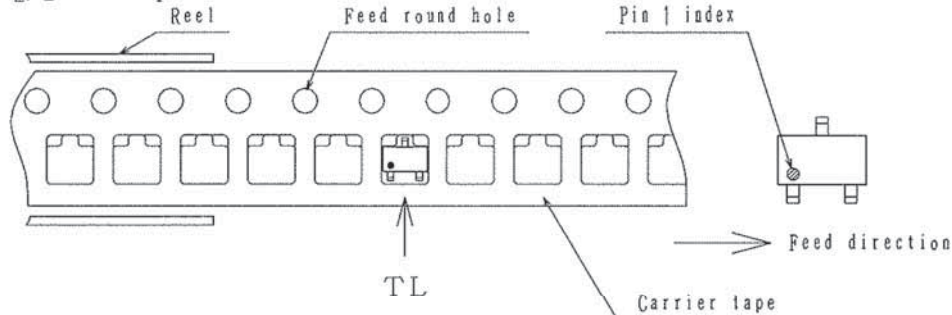


2. Taping configuration

2-1. Carrier tape size (unit:mm)



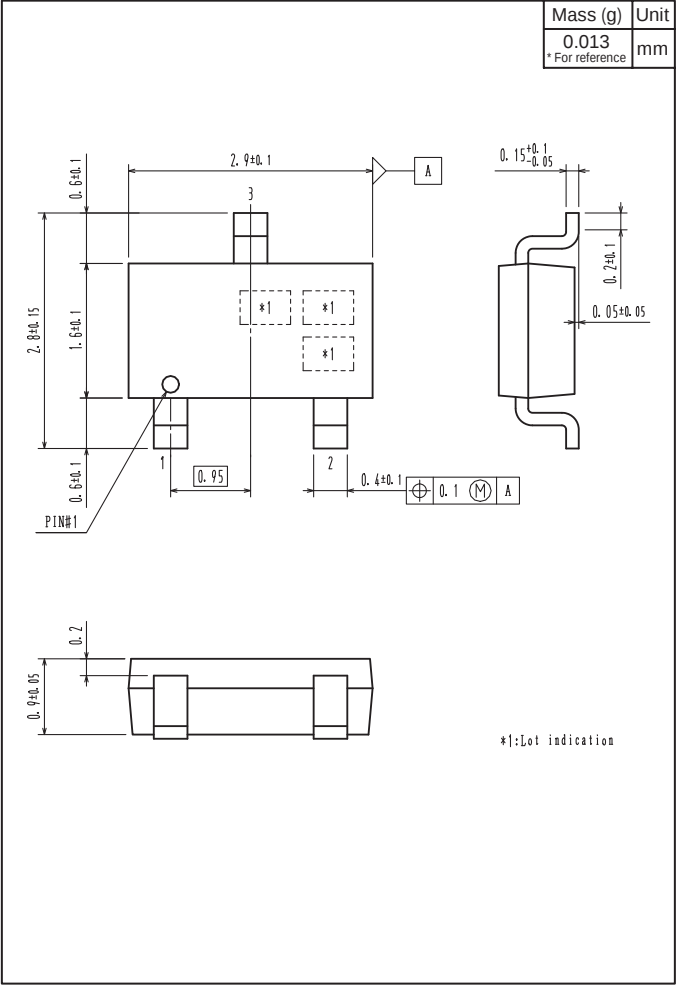
2-2. Device placement direction



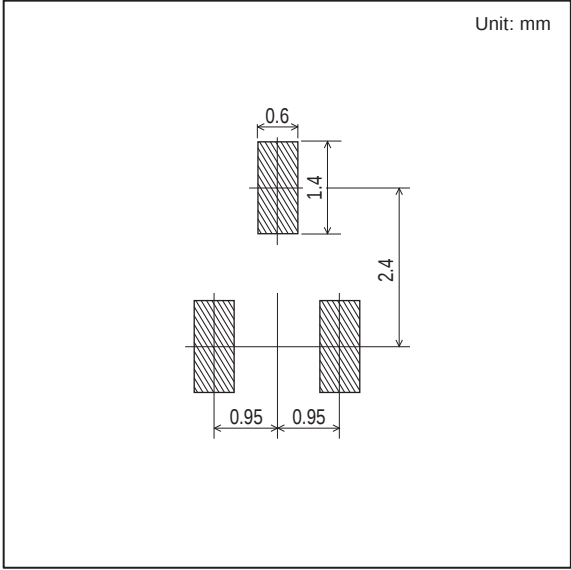
Those with one electrode terminal on the feed hole side.....TL

Outline Drawing

CPH3140-TL-E, CPH3240-TL-E



Land Pattern Example



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